LB11967V

Monolithic Digital IC
For Variable Speed Fan Motor
Single-Phase Full-Wave Pre-Driver

ON Semiconductor®

http://onsemi.com

Overview

The LB11967V is a single-phase bipolar variable speed fan motor pre-driver that works with an external PWM signal. A highly efficient, quiet and low power consumption motor driver circuit, with a large variable speed, can be implemented by adding a small number of external components.

This device is optimal for driving large scale fan motors (with large air volume and large current) such as those used in servers and consumer products.

Functions

- Pre-driver for single-phase full-wave drive
  - ⇒ PNP-EMOS is used as an external power Transistor, enabling high-efficiency low-consumption drive by means of the low-saturation output and single-phase full-wave drive. (PMOS-NMOS also applicable)
- External PWM input enabling variable speed control
  - ⇒ Separately-excited upper direct PWM (f = 25kHz) control method, enabling highly silent speed control
- Compatible with 12V, 24V, and 48V power supplies
- Current limiter circuit incorporated
  - ⇒ Chopper type current limit at start
- Reactive current cut circuit incorporated
  - ⇒ Reactive current before phase change is cut to enable silent and low-consumption drive.
- Minimum speed setting pin
  - ⇒ Minimum speed can be set with external resistor. The start assistance circuit enables start at extremely low speed.
- Constant-voltage output pin for Hall bias
- Lock protection and automatic reset functions incorporated
- (Rotation speed detection), RD (Lock detection) output

Specifications

Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
V_{CC} maximum supply voltage	V_{CC} max		18	V
OUT pin maximum output current	I_{OUT} max		50	mA
OUT pin output withstand voltage	V_{OUT} max		18	V
HB maximum output current	I_{HB} max		10	mA
VTH input pin withstand voltage	V_{VTH} max		8	V
RD/FG output pin output withstand voltage	V_{RD}/V_{FG} max		18	V
RD/FG output current	I_{RD}/I_{FG} max		10	mA
Allowable power dissipation	Pd max	Mounted on a specified board*	800	mW
Operating temperature range	Topr		-30 to +95	°C
Storage temperature range	Tstg		-55 to +150	°C

*Specified board: 114.3mm × 76.1mm × 1.6mm, glass epoxy board.

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Recommended Operating Conditions at Ta = 25°C

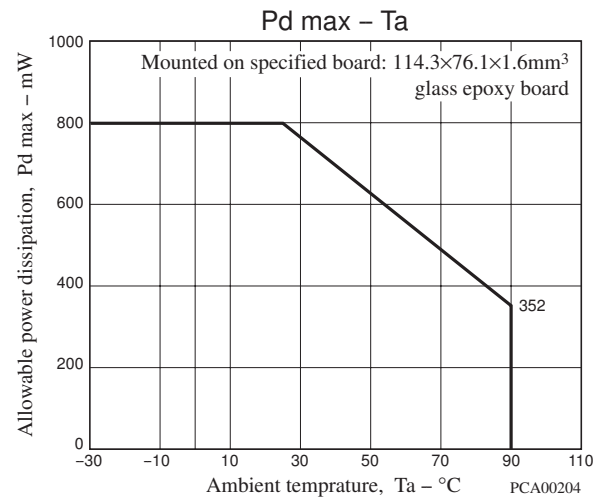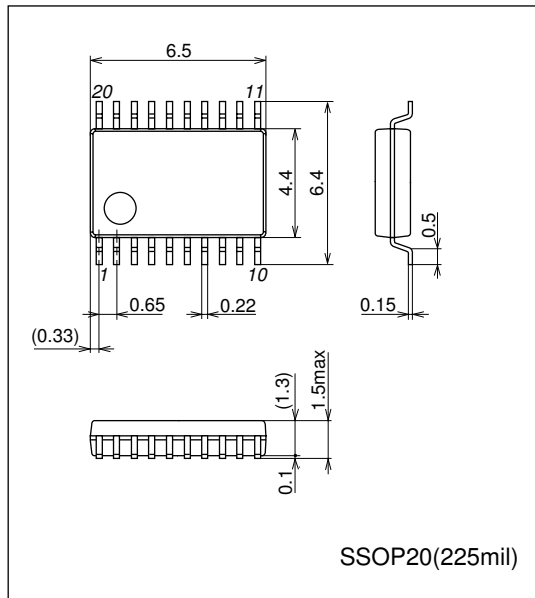| Parameter	Symbol	Conditions	Ratings	Unit
V_{CC} supply voltage	V_{CC}		6 to 16	V
VTH input level voltage range	VTH	Full speed mode	0 to 7	V
Hall input common phase input voltage range	VICM		0.2 to 3	V

Electrical Characteristics at Ta = 25°C, V_{CC} = 12V, unless otherwise specified.

Parameter	Symbol	Conditions	Ratings min	Ratings typ	Ratings max	Unit
Circuit current	$I_{CC}1$	During drive	6	10	14	mA
	$I_{CC}2$	During lock protection	6	10	14	mA
6VREG voltage	6VREG	I_{6VREG} = 5mA	5.80	6.0	6.15	V
HB voltage	V_{HB}	I_{HB} = 5mA	1.05	1.22	1.35	V
VOVER voltage	V_{VOVER}	I_{VOVER} = 1mA	12.0	12.8	13.6	V
CPWM-H level voltage	V_{CRH}		4.35	4.55	4.75	V
CPWM-L level voltage	V_{CRL}		1.45	1.65	1.85	V
CPWM oscillation frequency	FPWM	C = 100pF	18	25	32	kHz
CT pin H level voltage	V_{CTH}		3.4	3.6	3.8	V
CT pin L level voltage	V_{CTL}		1.4	1.6	1.8	V
ICT pin charge current	$I_{CT}1$	V_{CT} = 1.2V	1.6	2.0	2.5	µA
ICT pin discharge current	$I_{CT}2$	V_{CT} = 4.0V	0.16	0.20	0.28	µA
ICT charge/discharge current ratio	RCT	$I_{CT}1/I_{CT}2$	8	10	12	deg
OUT-N output voltage	V_{ON}	I_O = 20mA	4	10		V
OUT-P sink current	I_{OP}		15	20		mA
Hall input sensitivity	VHN	Zero peak value (including offset and hysteresis)		10	20	mV
RD/FG output pin L voltage	V_{RD}/V_{FG}	I_{RD}/I_{FG} = 5mA		0.15	0.3	V
RD/FG output pin leak current	I_{RDL}/I_{FGL}	V_{RD}/V_{FG} = 16V			30	µA

Package Dimensions

unit : mm (typ)

3179C

SSOP20(225mil)

Pd max – Ta

Mounted on specified board: $114.3 \times 76.1 \times 1.6mm^3$ glass epoxy board

Allowable power dissipation, Pd max – mW

Ambient temprature, Ta – °C

PCA00204

Pin Assignment

OUT2P	1		20	OUT1P
OUT2N	2		19	OUT1N
V_{CC}	3		18	VOVER
VLIM	4		17	SGND
SENSE	5	LB11967V	16	6VREG
RMI	6		15	ROFF
VTH	7		14	CT
CPWM	8		13	IN+
FG	9		12	HB
RD	10		11	IN-

Top view
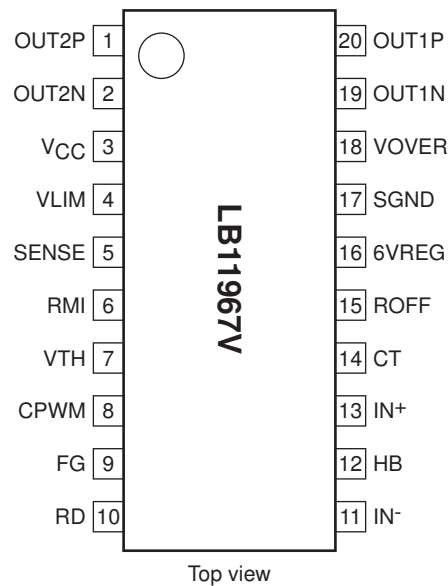
Truth Table

During full-speed rotation

IN-	IN+	CT	OUT1P	OUT1N	OUT2P	OUT2N	FG	RD	Mode
H	L	L	L	L	OFF	H	L	L	OUT1 → 2 drive
L	H		OFF	H	L	L	OFF		OUT2 → 1 drive
H	L	H	OFF	L	OFF	H	L	OFF	Lock protection
L	H		OFF	H	OFF	L	OFF		

VTH	CPWM	IN-	IN+	OUT1P	OUT1N	OUT2P	OUT2N	Mode
L	H	H	L	L	L	OFF	H	OUT1 → 2 drive
		L	H	OFF	H	L	L	OUT2 → 1 drive
H	L	H	L	OFF	L	OFF	H	During rotation
		L	H	OFF	H	OFF	L	Regeneration in lower Tr

CT

0.47 to 1μF

Discharge circuit

FG

RD

Discharge pulse

V_CC

6VREG

6VREG

ROFF

HB   Hall-Bias

HALL

IN+

IN−

Hysteresis AMP

Controller

Oscillation

OUT1N

OUT1P

OUT2N

OUT2P

RMI   VTH   CPWM   VLIM   SENSE   SGND

Sample Application Circuit 1 (12V)

CB=~0.022μF
RB=10kΩ
ROUT=100Ω
Vz=18V
SOP8901
RF
RFG,RRD=10k~100kΩ

V_CC
VOVER
HB
IN⁻
IN⁺
RMI
VTH
CPWM
CT
SGND

RD
FG
SENSE
VLIM
6VREG
ROFF
OUT1P
OUT1N
OUT2P
OUT2N

6VREG
PWM-IN
CP=100pF
25kHz
CT=0.47μF
R=0~5kΩ
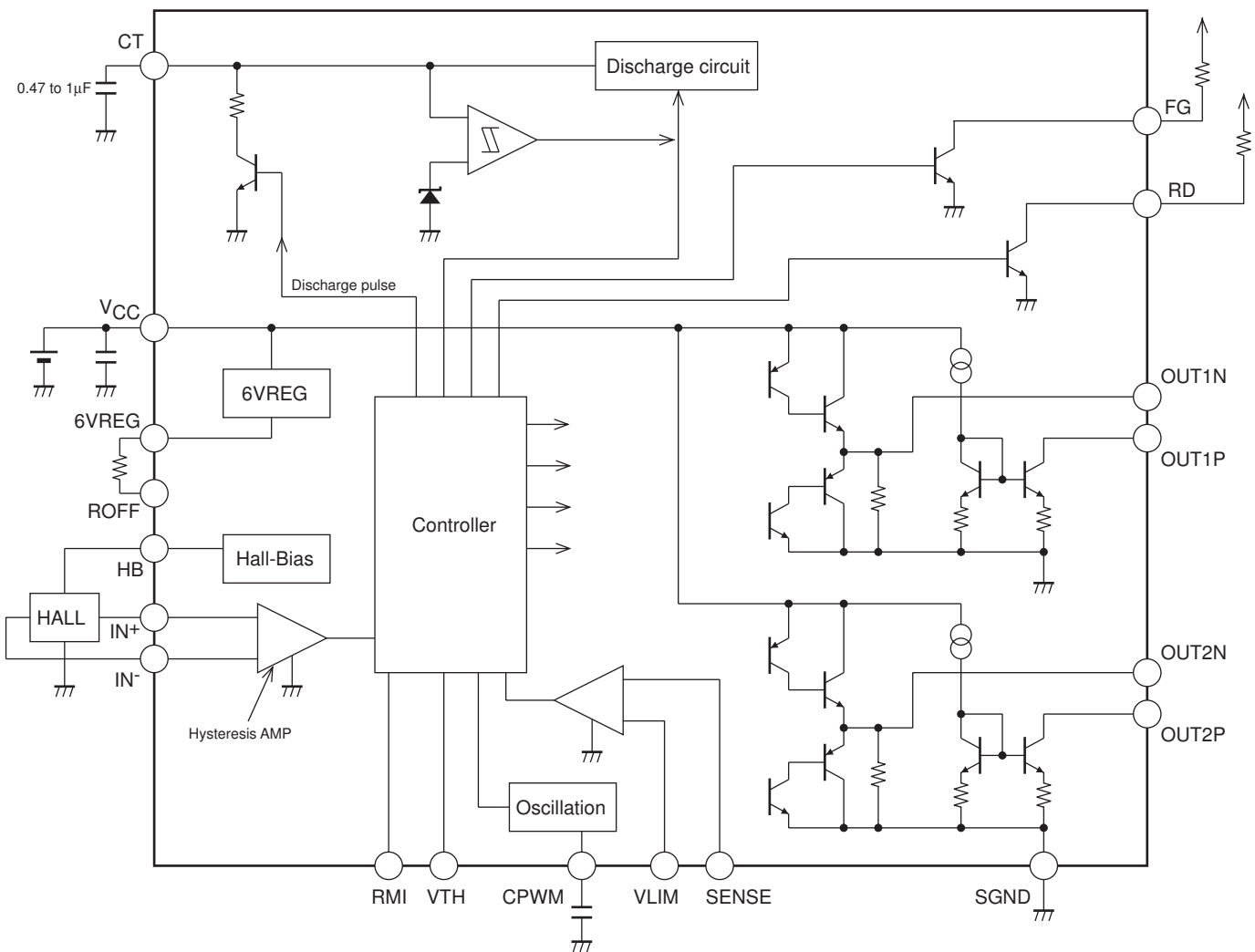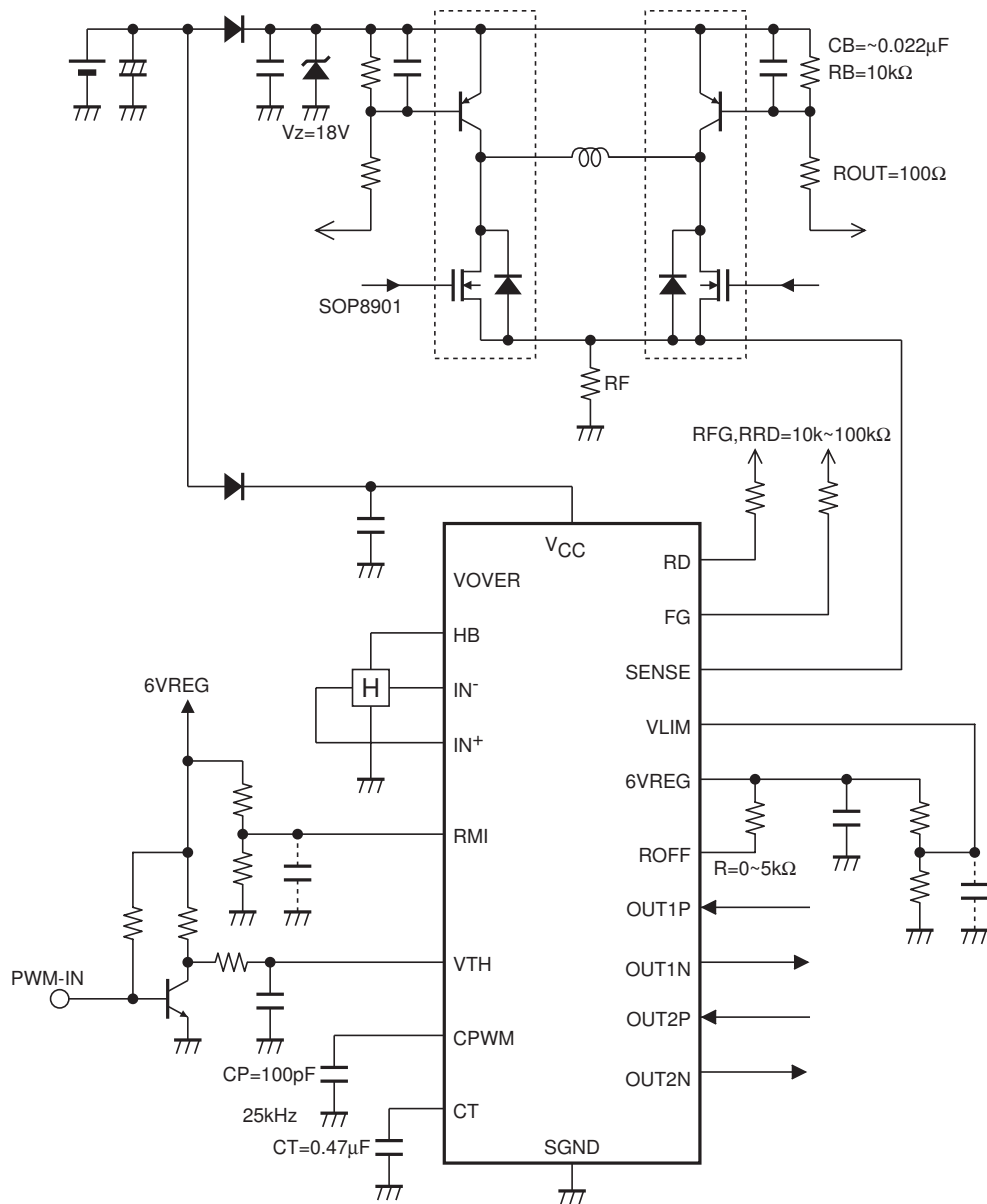
Sample Application Circuit 2 (24V, 48V)
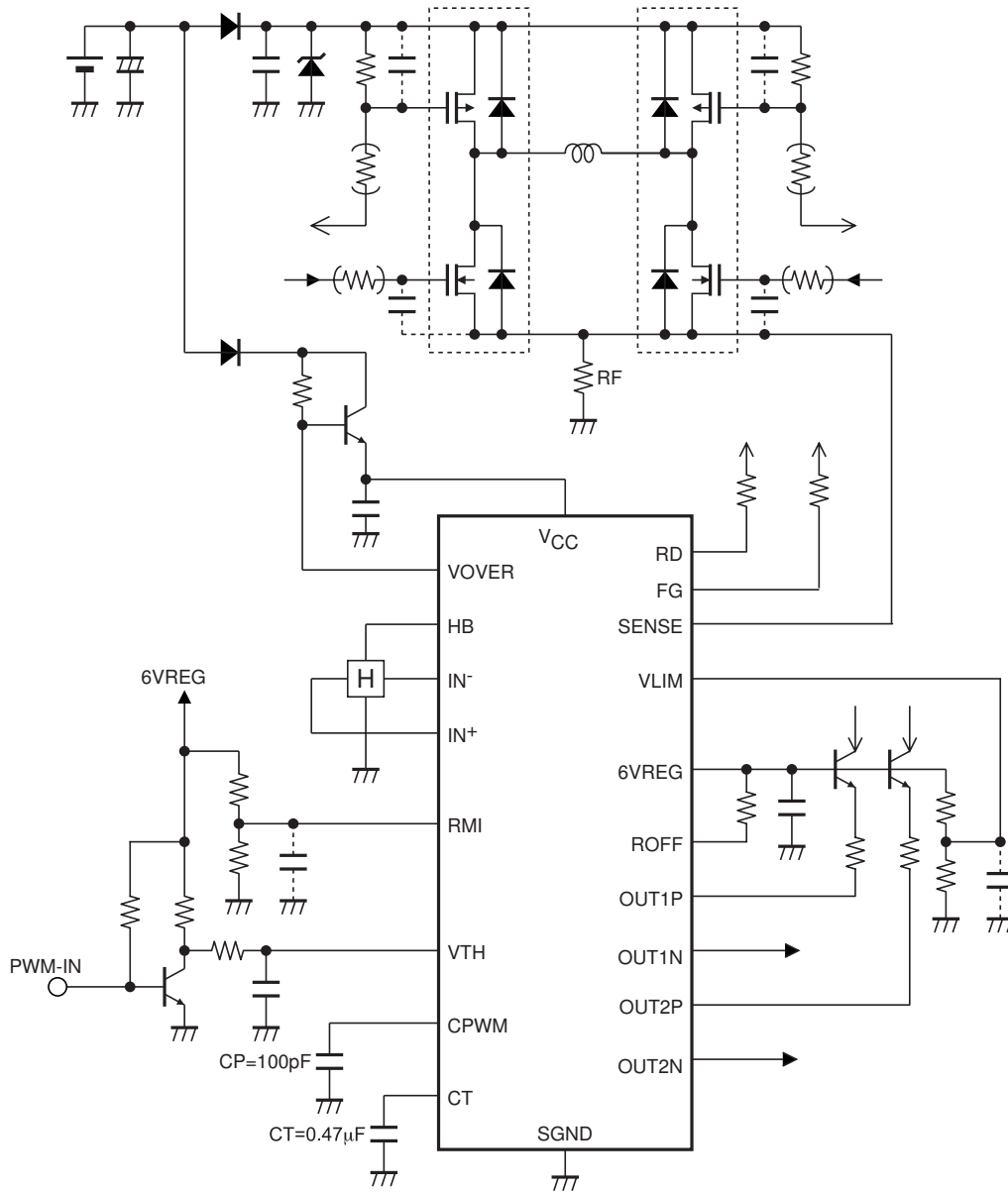
*1. <Power supply-GND wiring>
    SGND is connected to the control circuit power supply system.

*2. <Power stabilization capacitor for regeneration>
    For the CM capacitor that is a power stabilization capacitor for PWM drive and for absorption of kick-back, the capacitance uses 0.1μF or more. In this IC, the lower Transistor performs current regeneration by means of switching of upper Transistor. Connect CM between V_{CC} and GND with the thick pattern and along the shortest route.

*3. <Zener diode to stabilize power supply for regneration>
    Be sure to use the zener diode if kick-back causes excessive increase of the supply voltage because such increase damages IC.

*4. <Hall input>
    Wiring need to be short to prevent carrying of the noise. If the noise is carried, insert a capacitor between IN+ and IN-. The Hall input circuit is a comparator having a hysteresis of 20mV. It is recommended that the Hall input level is more than three times (60mVp-p) this hysteresis.

*5. <Capacitor to set the PWM oscillation frequency>
    With CP = 100pF, oscillation occurs at f = 25kHz and provides the basic frequency of PWM.

*6. <RD output>
    This is the open collector output, which outputs "L" during rotation and "H" at stop. This output is left open when not used.

*7. <FG output>
    This is the open collector output, which can detect the rotation speed using the FG output according to the phase shift. This output is left open when not used.

*8. <HB pin>
    This is a Hall element bias pin, that is, the constant-voltage output pin.

*9. <RMI pin>
    This is the minimum speed setting pin, which is pulled up with 6VREG when not used.
    When IC power may possibly be turned OFF first when the pin is used, be sure to insert a current limiting resistor to prevent inflow of the large current. (The same applies to the VTH pin.)

*10. <ROFF pin>
    This pin sets the soft switching time to cut the reactive current before phase change and is connected to 6VREG when not used.

*11. <VLIM pin>
    This pin activates the current limiter when the SENSE pin voltage is higher than the VLIM pin voltage and is connected to 6VREG when not used.
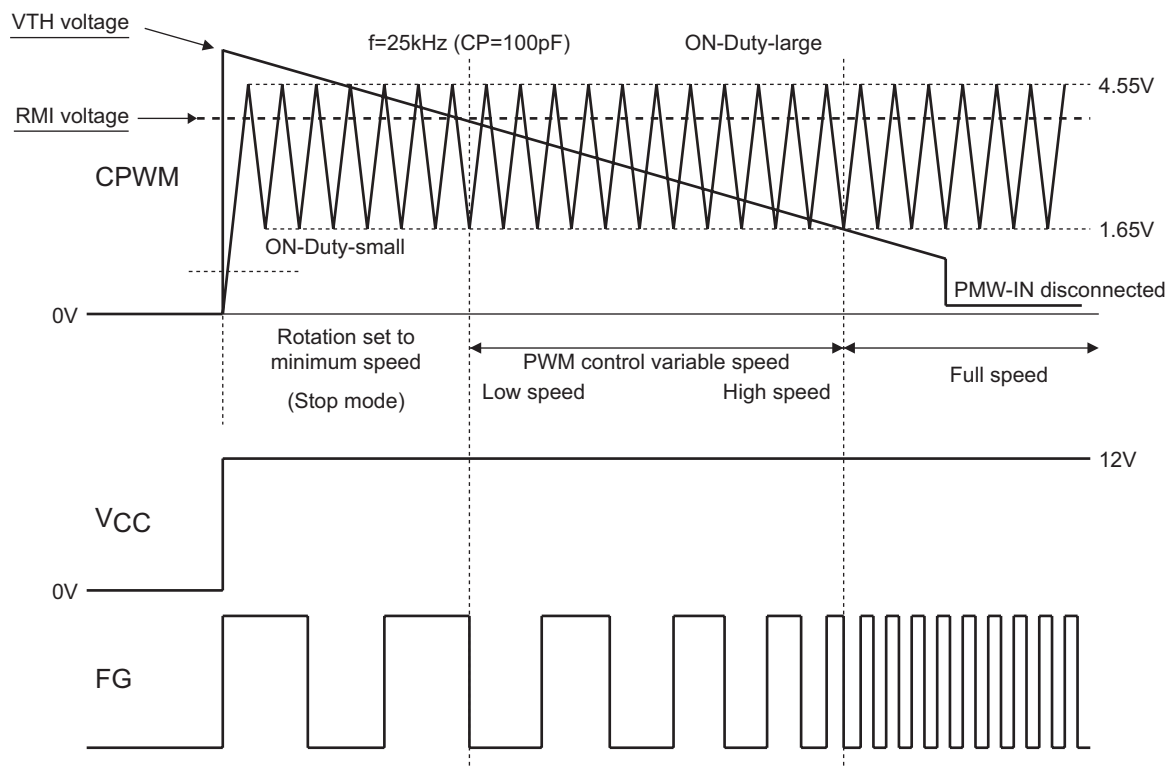
*12. <SENSE pin>
    This is connected to GND when not used.

*13. <VOVER pin>
    This is a pin for constant-voltage bias and should be used for application of 24V and 48V. (Refer to the sample application circuit.) Be sure to use the current limiting resistor. This is left open when not used.

Control Timing Chart

(1) Minimum speed setting (stop) mode

PWM-IN input is filtered to generate the VTH voltage. At low speed, the fan rotates with the minimum speed set with RMI pin during low speed. If the minimum speed is not set (RMI = 6VREG), the fan stops.

(2) Low⇔High speed mode

PWM control is made through comparison of oscillation and VTH voltages with CPWM changing between 1.6V⇔4.6V.

When the VTH voltage is lower, the IC switches to drive mode. When the VTH voltage is higher, the p-channel FET is turned off and coil current is regenerated through the low-side FET. Therefore, as the VTH voltage lowers, the output ON-DUTY increases, increasing the coil current and raising the motor speed.

The rotation speed is fed back by the FG output.

(3) Full speed mode

The full-speed mode becomes effective with the VTH voltage of 1.65V or less. (VTH must be equal to GND when the speed control is not to be made.)

(4) PWM-IN input disconnection mode

When the PWM-IN input pin is disconnected, VTH becomes 1.65V or les and the output enables full drive at 100%. The fan runs at full speed. (Refer to the sample application circuit.)